

ABSTRACT

The present invention provides a method for removal  
of boron from metal silicon inexpensively and extremely  
5 efficiently by a simple method, specifically, heating  
metal silicon containing boron as an impurity to its  
melting point to 2200°C to place it in a molten state,  
then adding a solid mainly comprised of silicon dioxide  
and a solid mainly comprised of one or both of a  
10 carbonate of an alkali metal or a hydrate of a carbonate  
of an alkali metal into said molten silicon so as to form  
a slag and remove the boron in the silicon.